

General Description

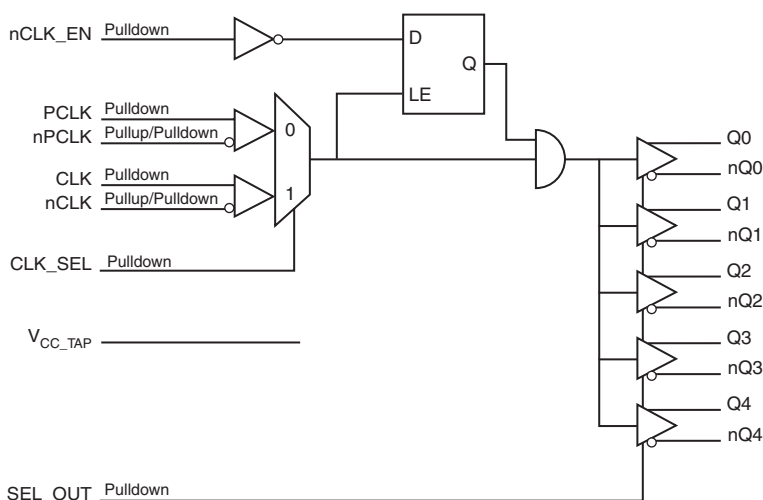
The ICS854S015I-01 is a low skew, high performance 1-to-5, 2.5V, 3.3V Differential-to-LVPECL/LVDS Fanout Buffer. The ICS854S015I-01 has two selectable differential clock inputs.

Guaranteed output and part-to-part skew characteristics make the ICS854S015I-01 ideal for those applications demanding well defined performance and repeatability.

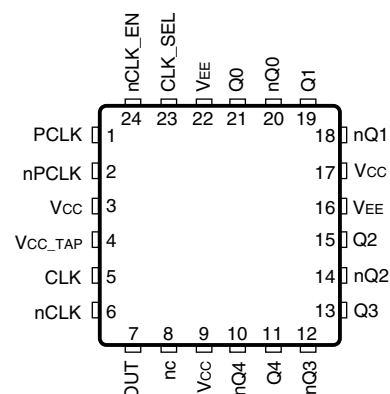
Features

- Five differential LVPECL or LVDS output pairs
- Two differential clock input pairs
- CLK, nCLK pair can accept the following differential input levels: LVDS, LVPECL, LVHSTL, HCSL
- PCLK, nPCLK can accept the following input levels: LVPECL, LVDS, CML
- Either CLK or PCLK inputs can be configured to accept single-ended inputs
- Maximum output frequency: 2GHz
- Additive phase jitter, RMS: 0.065ps (maximum), 3.3V, 156.25MHz, 12kHz – 5MHz)
- Output Skew: 55ps (maximum)
- Propagation delay: 570ps (typical) @ 3.3V
- Full 3.3V or 2.5V supply modes
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

Block Diagram



Pin Assignment



ICS854S015I-01

24-Lead VFQFN

4mm x 4mm x 0.925mm package body

K Package

Top View

Table 1. Pin Descriptions

| Number | Name | Type | | Description |
|----------|---------------|--------|---------------------|---|
| 1 | PCLK | Input | Pulldown | Non-inverting differential LVPECL clock input. |
| 2 | nPCLK | Input | Pullup/ Pulldown | Inverting differential LVPECL clock input. $V_{CC}/2$ default when left floating. |
| 3, 9, 17 | V_{CC} | Power | | Positive supply pins. |
| 4 | V_{CC_TAP} | Power | | Power supply pin. See Table 3C. |
| 5 | CLK | Input | Pulldown | Non-inverting differential clock input. |
| 6 | nCLK | Input | Pullup/ Pulldown | Inverting differential clock input. $V_{CC}/2$ default when left floating. |
| 7 | SEL_OUT | Input | Pulldown | Output select pin. When LOW, selects LVDS output levels. When HIGH, selects LVPECL output levels. See Table 3. LVCMOS/LVTTL interface levels. |
| 8 | nc | Unused | | No-connect. |
| 10, 11 | nQ4, Q4 | Output | | Differential output pair. LVDS or LVPECL interface levels. |
| 12, 13 | nQ3, Q3 | Output | | Differential output pair. LVDS or LVPECL interface levels. |
| 14, 15 | nQ2, Q2 | Output | | Differential output pair. LVDS or LVPECL interface levels. |
| 16, 22 | V_{EE} | Power | | Negative supply pins. |
| 18, 19 | nQ1, Q1 | Output | | Differential output pair. LVDS or LVPECL interface levels. |
| 20, 21 | nQ0, Q0 | Output | | Differential output pair. LVDS or LVPECL interface levels. |
| 23 | CLK_SEL | Input | Pulldown | Clock select input. When HIGH, selects CLK, nCLK inputs. When LOW, selects PCLK, nPCLK inputs. LVTTL / LVCMOS interface levels. |
| 24 | nCLK_EN | Input | Pulldown | Synchronizing clock enable. When LOW, clock outputs follow clock input. When HIGH, Qx outputs are forced low, nQx outputs are forced high. LVTTL / LVCMOS interface levels. |

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------------|--------------------------|-----------------|---------|---------|---------|------------|
| C_{IN} | Input Capacitance | | | 2 | | pF |
| $R_{PULLDOWN}$ | Input Pulldown Resistor | | | 50 | | k Ω |
| $R_{VCC/2}$ | Pullup/Pulldown Resistor | | | 50 | | k Ω |

Function Tables

Table 3A. Control Input Function Table

| Inputs | | | Outputs | |
|---------|---------|-----------------|---------------|----------------|
| nCLK_EN | CLK_SEL | Selected Source | Q[0:4] | nQ[0:4] |
| 0 | 0 | PCLK, nPCLK | Enabled | Enabled |
| 0 | 1 | CLK, nCLK | Enabled | Enabled |
| 1 | 0 | PCLK, nPCLK | Disabled; Low | Disabled; High |
| 1 | 1 | CLK, nCLK | Disabled; Low | Disabled; High |

After nCLK_EN switches, the clock outputs are disabled or enabled following a falling input clock edge as shown in Figure 1. In the active mode, the state of the outputs are a function of the PCLK, nPCLK and CLK, nCLK inputs as described in Table 3B.

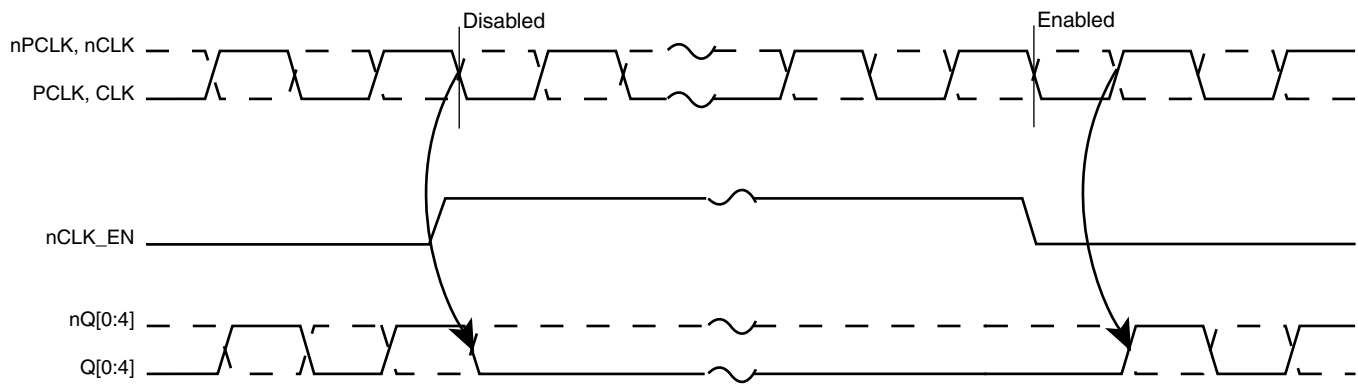


Figure 1. nCLK_EN Timing Diagram

Table 3B. Clock Input Function Table

| Inputs | | Outputs | | Input to Output Mode | Polarity |
|-------------|---------------|---------|---------|------------------------------|---------------|
| PCLK or CLK | nPCLK or nCLK | Q[0:4] | nQ[0:4] | | |
| 0 | 1 | LOW | HIGH | Differential to Differential | Non-Inverting |
| 1 | 0 | HIGH | LOW | Differential to Differential | Non-Inverting |

Table 3C. V_{CC_TAP} Function Table

| Outputs | Output Level Supply | V _{CC_TAP} |
|-----------------|---------------------|---------------------|
| Q[0:4], nQ[0:4] | | |
| LVPECL | 2.5V | 2.5V |
| LVPECL | 3.3V | 3.3V |
| LVDS | 2.5V | 2.5V |
| LVDS | 3.3V | Float |

Table 3D. SEL_OUT Function Table

| Input | Outputs |
|-------------|-----------------|
| SEL_OUT | Q[0:4], nQ[0:4] |
| 0 (default) | LVDS |
| 1 | LVPECL |

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

| Item | Rating |
|--|--------------------------|
| Supply Voltage, V_{CC} | 4.6V |
| Inputs, V_I | -0.5V to $V_{CC} + 0.5V$ |
| Outputs, I_O (LVPECL) Continuous Current Surge Current | 50mA 100mA |
| Outputs, I_O (LVDS) Continuous Current Surge Current | 10mA 15mA |
| Package Thermal Impedance, θ_{JA} | 49.5°C/W (0 mps) |
| Storage Temperature, T_{STG} | -65°C to 150°C |

DC Electrical Characteristics

Table 4A. LVPECL Power Supply DC Characteristics, $V_{CC} = V_{CC_TAP} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------|-------------------------|-----------------|---------|---------|---------|-------|
| V_{CC} | Positive Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| V_{CC_TAP} | Power Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| I_{EE} | Power Supply Current | | | | 85 | mA |
| I_{TAP} | Power Supply Current | | | | 5 | mA |

Table 4B. LVPECL Power Supply DC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------|-------------------------|-----------------|---------|---------|---------|-------|
| V_{CC} | Positive Supply Voltage | | 2.375 | 2.5 | 2.625 | V |
| V_{CC_TAP} | Power Supply Voltage | | 2.375 | 2.5 | 2.625 | V |
| I_{EE} | Power Supply Current | | | | 78 | mA |
| I_{TAP} | Power Supply Current | | | | 5 | mA |

Table 4C. LVDS Power Supply DC Characteristics, $V_{CC} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|-------------------------|-----------------|---------|---------|---------|-------|
| V_{CC} | Positive Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| I_{CC} | Power Supply Current | | | | 160 | mA |

NOTE: V_{CC_TAP} is left floating for 3.3V operation.**Table 4D. LVDS Power Supply DC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ\text{C}$ to 85°C**

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------|-------------------------|-----------------|---------|---------|---------|-------|
| V_{CC} | Positive Supply Voltage | | 2.375 | 2.5 | 2.625 | V |
| V_{CC_TAP} | Power Supply Voltage | | 2.375 | 2.5 | 2.625 | V |
| I_{CC} | Power Supply Current | | | | 150 | mA |
| I_{CC_TAP} | Power Supply Current | | | | 5 | mA |

Table 4E. LVCMOS/LVTTL DC Characteristics, $V_{CC} = 3.3V \pm 5\%$ or $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ\text{C}$ to 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|--------------------|--|---------|---------|----------------|---------------|
| V_{IH} | Input High Voltage | $V_{CC} = 3.465V$ | 2.2 | | $V_{CC} + 0.3$ | V |
| | | $V_{CC} = 2.625V$ | 1.7 | | $V_{CC} + 0.3$ | V |
| V_{IL} | Input Low Voltage | $V_{CC} = 3.465V$ | -0.3 | | 0.8 | V |
| | | $V_{CC} = 2.625V$ | -0.3 | | 0.7 | V |
| I_{IH} | Input High Current | CLK_SEL, SEL_OUT, nCLK_EN $V_{CC} = V_{IN} = 3.465V$ or $2.625V$ | | | 150 | μA |
| I_{IL} | Input Low Current | CLK_SEL, SEL_OUT, nCLK_EN $V_{CC} = 3.465V$ or $2.625V$, $V_{IN} = 0V$ | -10 | | | μA |

Table 4F. Differential DC Characteristics, $V_{CC} = 3.3V \pm 5\%$ or $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ\text{C}$ to 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------|-----------------------------------|---|----------------|---------|-----------------|---------------|
| I_{IH} | Input High Current | CLK, nCLK $V_{CC} = V_{IN} = 3.465V$ | | | 150 | μA |
| I_{IL} | Input Low Current | CLK $V_{CC} = 3.465V$, $V_{IN} = 0V$ | -10 | | | μA |
| | | nCLK $V_{CC} = 3.465V$, $V_{IN} = 0V$ | -150 | | | μA |
| V_{PP} | Peak-to-Peak Input Voltage | CLK, nCLK | 0.15 | | 1.3 | V |
| V_{CMR} | Common Mode Input Voltage; NOTE 1 | CLK, nCLK | $V_{EE} + 0.5$ | | $V_{CC} - 0.85$ | V |

NOTE 1. Common mode voltage is defined as V_{IH} .

Table 4G. LVPECL DC Characteristics, $V_{CC} = V_{CC_TAP} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------|-----------------------------------|---|----------------|---------|----------------|---------|
| I_{IH} | Input High Current | PCLK, nPCLK $V_{CC} = V_{IN} = 3.465V$ | | | 150 | μA |
| I_{IL} | Input Low Current | PCLK $V_{CC} = 3.465V, V_{IN} = 0V$ | -10 | | | μA |
| | | nPCLK $V_{CC} = 3.465V, V_{IN} = 0V$ | -150 | | | μA |
| V_{PP} | Peak-to-Peak Input Voltage | PCLK, nPCLK | 0.15 | | 1.3 | V |
| V_{CMR} | Common Mode Input Voltage; NOTE 1 | PCLK, nPCLK | $V_{EE} + 1.2$ | | V_{CC} | V |
| V_{OH} | Output High Voltage; NOTE 2 | SEL_OUT = 1 | $V_{CC} - 1.4$ | | $V_{CC} - 0.9$ | V |
| V_{OL} | Output Low Voltage; NOTE 2 | SEL_OUT = 1 | $V_{CC} - 2.0$ | | $V_{CC} - 1.7$ | V |
| V_{SWING} | Peak-to-peak Output Voltage Swing | SEL_OUT = 1 | 0.6 | | 1.0 | V |

NOTE 1. Common mode voltage is defined as V_{IH} .NOTE 2: Outputs terminated with 50Ω to $V_{CC} - 2V$.**Table 4H. LVPECL DC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$**

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------|-----------------------------------|---|----------------|---------|----------------|---------|
| I_{IH} | Input High Current | PCLK, nPCLK $V_{CC} = V_{IN} = 2.625V$ | | | 150 | μA |
| I_{IL} | Input Low Current | PCLK $V_{CC} = 2.625V, V_{IN} = 0V$ | -10 | | | μA |
| | | nPCLK $V_{CC} = 2.625V, V_{IN} = 0V$ | -150 | | | μA |
| V_{PP} | Peak-to-Peak Input Voltage | PCLK, nPCLK | 0.15 | | 1.3 | V |
| V_{CMR} | Common Mode Input Voltage; NOTE 1 | PCLK, nPCLK | $V_{EE} + 1.2$ | | V_{CC} | V |
| V_{OH} | Output High Voltage; NOTE 2 | SEL_OUT = 1 | $V_{CC} - 1.4$ | | $V_{CC} - 0.9$ | V |
| V_{OL} | Output Low Voltage; NOTE 2 | SEL_OUT = 1 | $V_{CC} - 2.0$ | | $V_{CC} - 1.5$ | V |
| V_{SWING} | Peak-to-peak Output Voltage Swing | SEL_OUT = 1 | 0.4 | | 1.0 | V |

NOTE 1. Common mode voltage is defined as V_{IH} .NOTE 2: Outputs terminated with 50Ω to $V_{CC} - 2V$.**Table 4I. LVDS DC Characteristics, $V_{CC} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$**

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------|-----------------------------|-----------------|---------|---------|---------|-------|
| V_{OD} | Differential Output Voltage | SEL_OUT = 0 | 247 | | 454 | mV |
| ΔV_{OD} | V_{OD} Magnitude Change | SEL_OUT = 0 | | | 50 | mV |
| V_{OS} | Offset Voltage | SEL_OUT = 0 | 1.125 | | 1.375 | V |
| ΔV_{OS} | V_{OS} Magnitude Change | SEL_OUT = 0 | | | 50 | mV |

Table 4J. LVDS DC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------|-----------------------------|-----------------|---------|---------|---------|-------|
| V_{OD} | Differential Output Voltage | SEL_OUT = 0 | 247 | | 454 | mV |
| ΔV_{OD} | V_{OD} Magnitude Change | SEL_OUT = 0 | | | 50 | mV |
| V_{OS} | Offset Voltage | SEL_OUT = 0 | 1.105 | | 1.375 | V |
| ΔV_{OS} | V_{OS} Magnitude Change | SEL_OUT = 0 | | | 50 | mV |

AC Electrical Characteristics

Table 5A. LVPECL AC Characteristics, $V_{CC} = V_{CC_TAP} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------------|--|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | | | 2 | GHz |
| t_{PD} | Propagation Delay, Low-to-High; NOTE 1 | | 300 | | 800 | ps |
| $tsk(o)$ | Output Skew; NOTE 2, 3 | | | | 55 | ps |
| $tsk(pp)$ | Part-to-Part Skew; NOTE 3, 4 | | | | 250 | ps |
| f_{jit} | Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section | 156.25MHz, Integration Range: 12kHz - 5MHz | | 0.046 | 0.065 | ps |
| | | 156.25MHz, Integration Range: 12kHz - 20MHz | | 0.083 | 0.120 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 5MHz | | 0.034 | 0.059 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 20MHz | | 0.068 | 0.094 | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | 80 | | 220 | ps |
| odc | Output Duty Cycle | | 45 | | 55 | % |
| $MUX_{ISOLATION}$ | MUX Isolation | @ 100MHz | | 85 | | dB |

All parameters measured at $f_{OUT} \leq 1GHz$ unless noted otherwise.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured from the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same temperature, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

Table 5B. LVPECL AC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------------|--|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | | | 2 | GHz |
| t_{PD} | Propagation Delay, Low-to-High; NOTE 1 | | 300 | | 800 | ps |
| $tsk(o)$ | Output Skew; NOTE 2, 3 | | | | 55 | ps |
| $tsk(pp)$ | Part-to-Part Skew; NOTE 3, 4 | | | | 250 | ps |
| f_{jit} | Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section | 156.25MHz, Integration Range: 12kHz - 5MHz | | 0.054 | 0.079 | ps |
| | | 156.25MHz, Integration Range: 12kHz - 20MHz | | 0.097 | 0.134 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 5MHz | | 0.050 | 0.067 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 20MHz | | 0.099 | 0.131 | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | 80 | | 210 | ps |
| odc | Output Duty Cycle | | 45 | | 55 | % |
| $MUX_{ISOLATION}$ | MUX Isolation | @ 100MHz | | 85 | | dB |

For NOTES, see Table 5A above.

Table 5C. LVDS AC Characteristics, $V_{CC} = 3.3V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------------|--|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | | | 2 | GHz |
| t_{PD} | Propagation Delay, Low-to-High; NOTE 1 | | 300 | | 800 | ps |
| $tsk(o)$ | Output Skew; NOTE 2, 3 | | | | 55 | ps |
| $tsk(pp)$ | Part-to-Part Skew; NOTE 3, 4 | | | | 250 | ps |
| \bar{f}_{jit} | Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section | 156.25MHz, Integration Range: 12kHz - 5MHz | | 0.048 | 0.074 | ps |
| | | 156.25MHz, Integration Range: 12kHz - 20MHz | | 0.096 | 0.146 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 5MHz | | 0.035 | 0.054 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 20MHz | | 0.074 | 0.097 | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | 80 | | 200 | ps |
| odc | Output Duty Cycle | | 45 | | 55 | % |
| $MUX_{ISOLATION}$ | MUX Isolation | @ 100MHz | | 85 | | dB |

All parameters measured at $f_{OUT} \leq 1GHz$ unless noted otherwise.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured from the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: Defined as skew between outputs on different devices operating at the same supply voltage, same temperature, same frequency and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

Table 5D. LVDS AC Characteristics, $V_{CC} = V_{CC_TAP} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

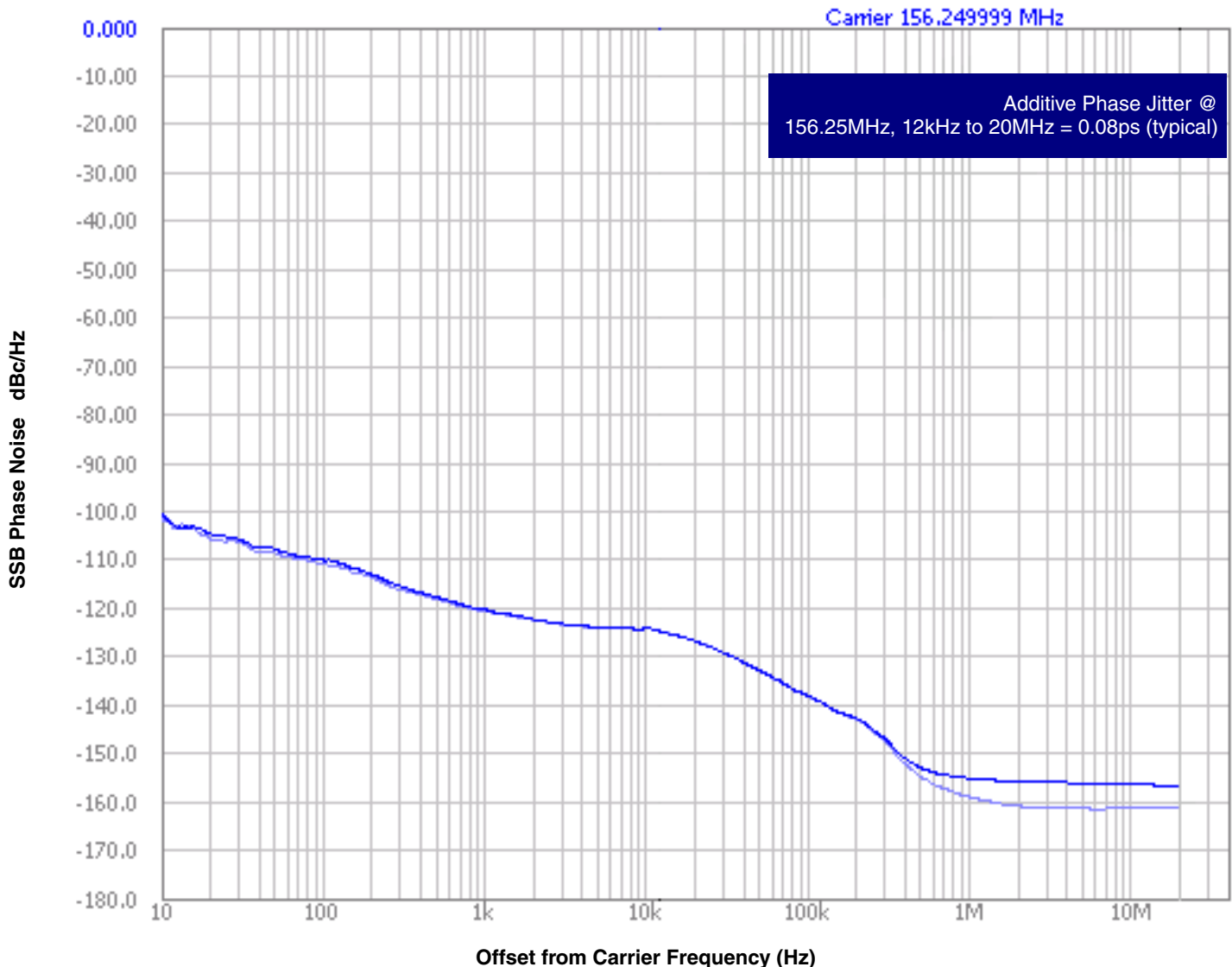
| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-------------------|--|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | | | 2 | GHz |
| t_{PD} | Propagation Delay, Low-to-High; NOTE 1 | | 300 | | 800 | ps |
| $tsk(o)$ | Output Skew; NOTE 2, 3 | | | | 55 | ps |
| $tsk(pp)$ | Part-to-Part Skew; NOTE 3, 4 | | | | 250 | ps |
| \bar{f}_{jit} | Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section | 156.25MHz, Integration Range: 12kHz - 5MHz | | 0.049 | 0.074 | ps |
| | | 156.25MHz, Integration Range: 12kHz - 20MHz | | 0.098 | 0.139 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 5MHz | | 0.037 | 0.060 | ps |
| | | 245.76MHz, Integration Range: 12kHz - 20MHz | | 0.076 | 0.102 | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | 80 | | 200 | ps |
| odc | Output Duty Cycle | | 45 | | 55 | % |
| $MUX_{ISOLATION}$ | MUX Isolation | @ 100MHz | | 85 | | dB |

For NOTES, see Table 5C above.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the **dBc Phase Noise**. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio

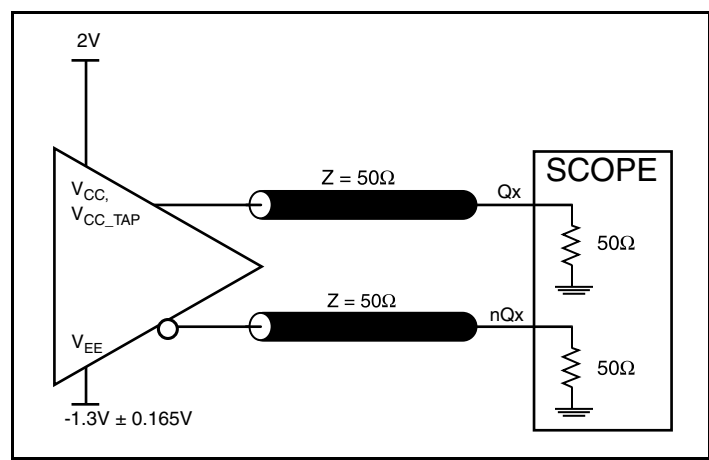
of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a **dBc** value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



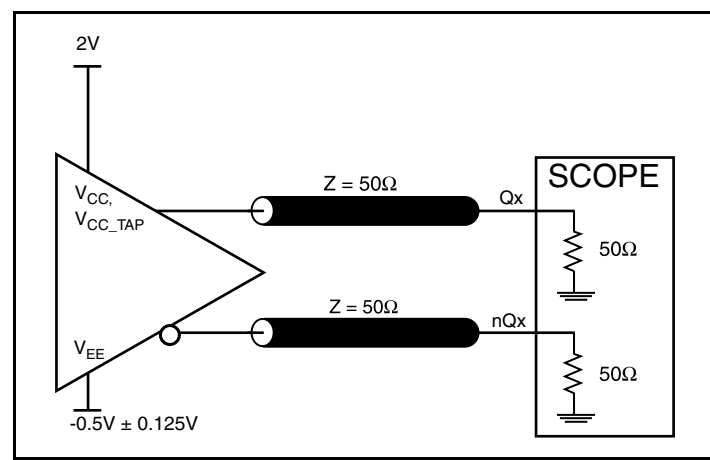
As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

The source generator used is, "Rhode & Schwarz SMA 100A Signal Generator, via the clock synthesis as the external input to drive the input clock."

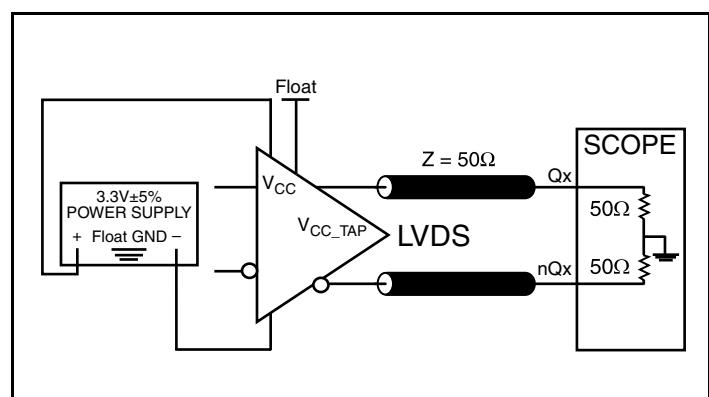
Parameter Measurement Information



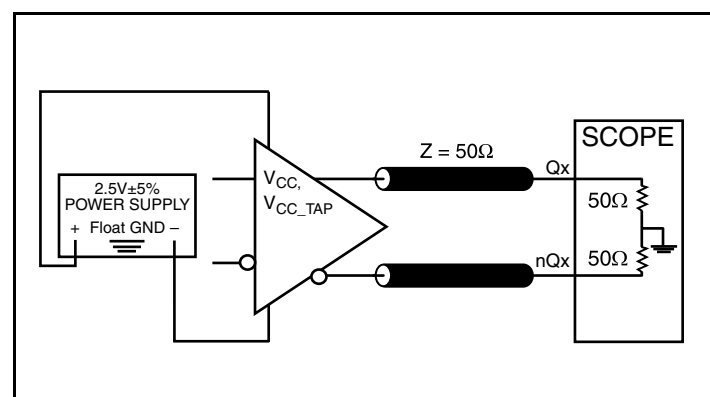
3.3V LVPECL Output Load AC Test Circuit



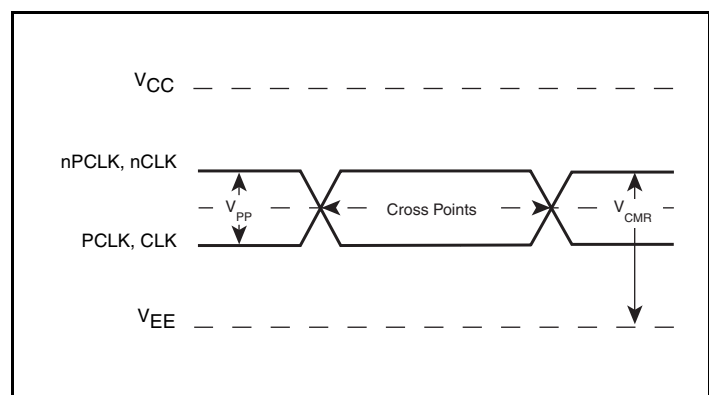
2.5V LVPECL Output Load AC Test Circuit



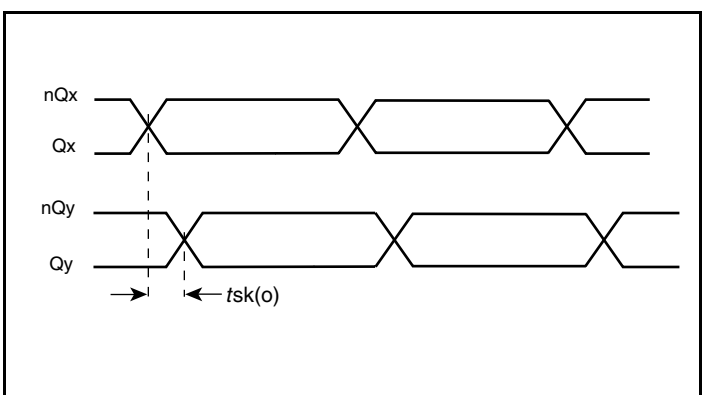
3.3V LVDS Output Load AC Test Circuit



2.5V LVDS Output Load AC Test Circuit

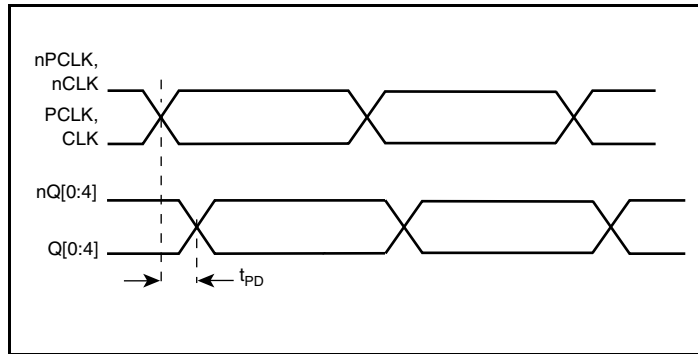


Differential Input Level

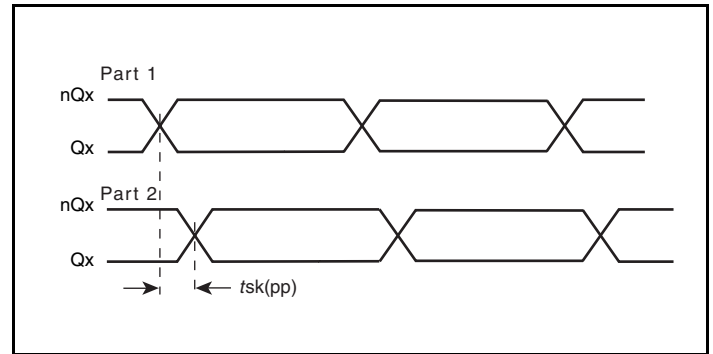


Output Skew

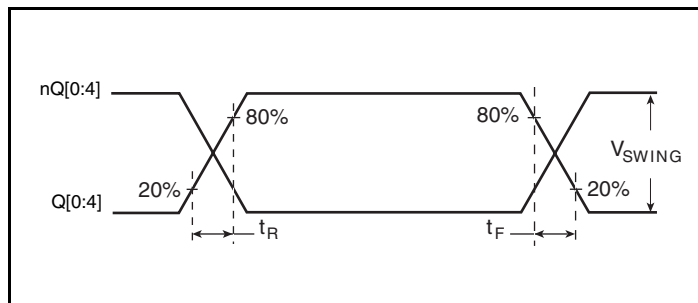
Parameter Measurement Information, continued



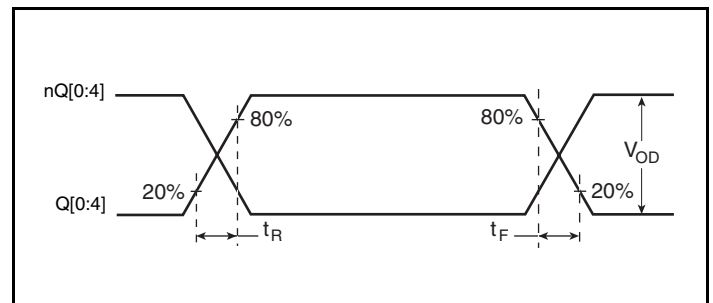
Propagation Delay



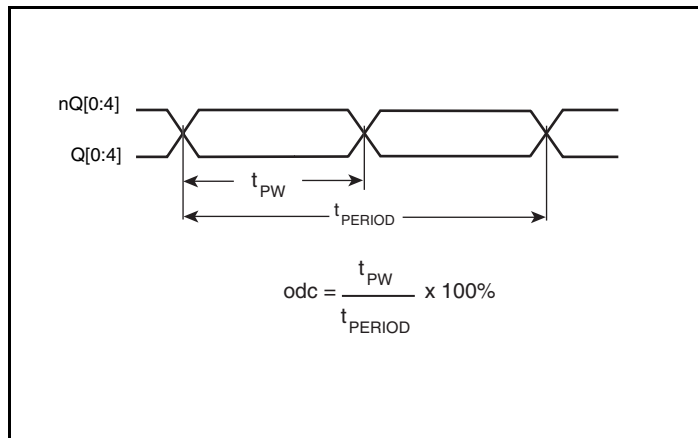
Part-to-Part Skew



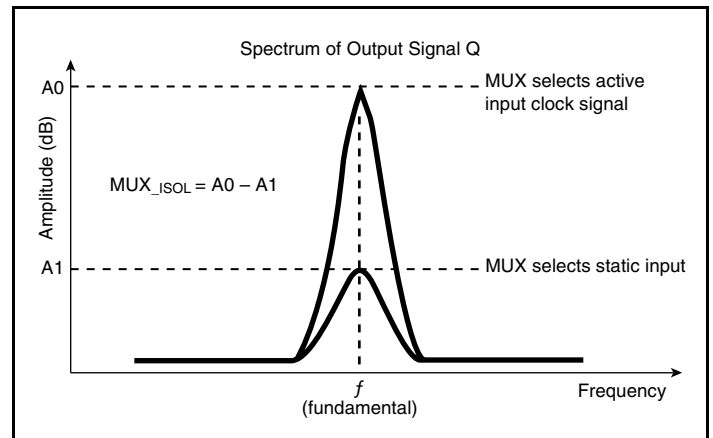
LVPECL Output Rise/Fall Time



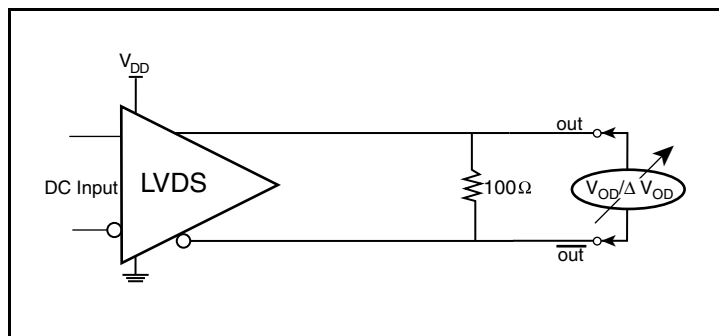
LVDS Output Rise/Fall Time



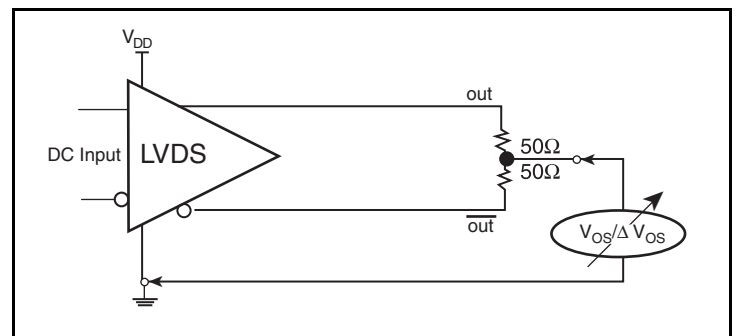
Output Duty Cycle/Pulse Width/Period



MUX Isolation



Differential Output Voltage Setup



Offset Voltage Setup

Applications Information

Recommendations for Unused Input and Output Pins

Inputs:

PCLK/nPCLK Inputs

For applications not requiring the use of a differential input, both the PCLK and nPCLK pins can be left floating. Though not required, but for additional protection, a 1k Ω resistor can be tied from PCLK to ground.

CLK/nCLK Inputs

For applications not requiring the use of a differential input, both the CLK and nCLK pins can be left floating. Though not required, but for additional protection, a 1k Ω resistor can be tied from CLK to ground.

LVC MOS Control Pins

All control pins have internal pulldowns; additional resistance is not required but can be added for additional protection. A 1k Ω resistor can be used.

Outputs:

LVPECL Outputs

All unused LVPECL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

LVDS Outputs

All unused LVDS output pairs can be either left floating or terminated with 100 Ω across. If they are left floating, there should be no trace attached.

Wiring the Differential Input to Accept Single-Ended Levels

Figure 2 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{CC}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is 2.5V and $V_{CC} = 3.3V$, R1 and R2 value should be adjusted to set V_{REF} at 1.25V. The values below are for when both the single ended swing and V_{CC} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (R_o) and the series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission

line impedance. For most 50 Ω applications, R3 and R4 can be 100 Ω . The values of the resistors can be increased to reduce the loading for slower and weaker LVC MOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVC MOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V_{IL} cannot be less than -0.3V and V_{IH} cannot be more than $V_{CC} + 0.3V$. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

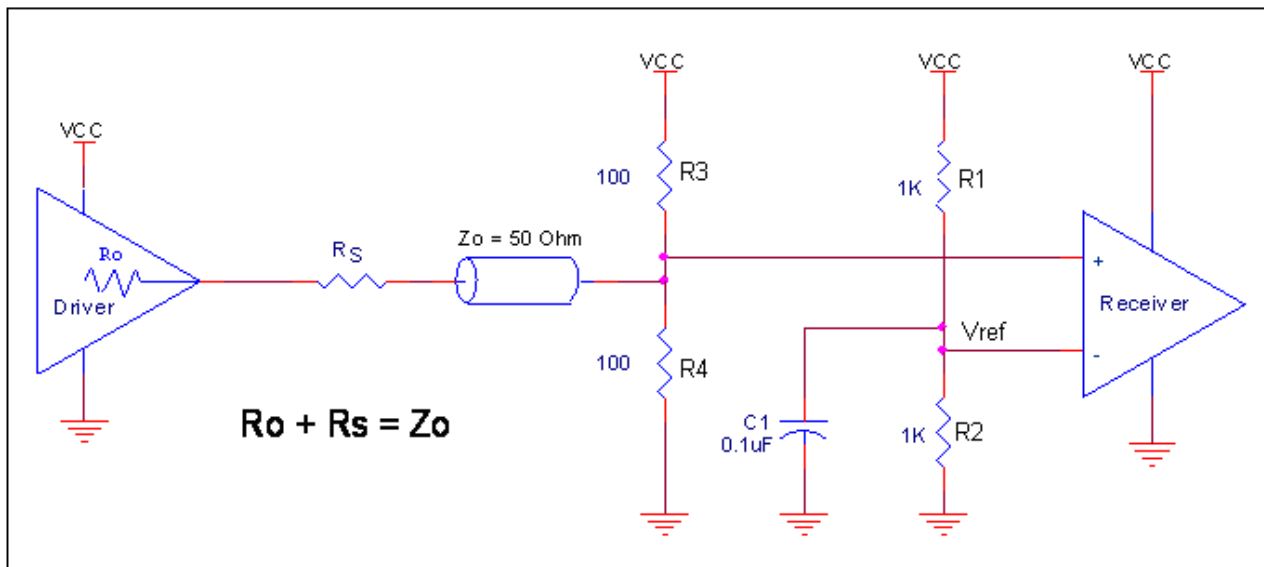


Figure 2. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

3.3V LVPECL Clock Input Interface

The PCLK/nPCLK accepts LVPECL, CML, LVDS and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 3A to 3E* show interface examples for the PCLK/nPCLK input driven by the most common driver types.

The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

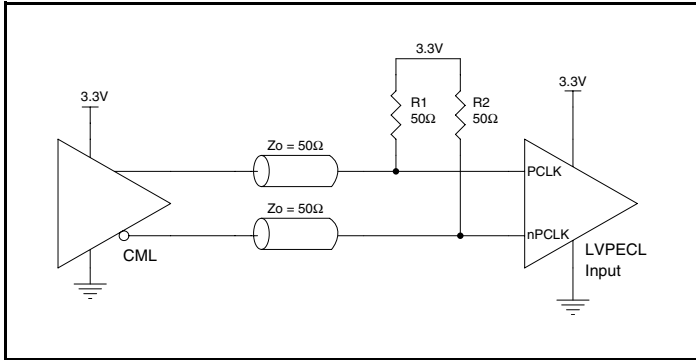


Figure 3A. PCLK/nPCLK Input Driven by an Open Collector CML Driver

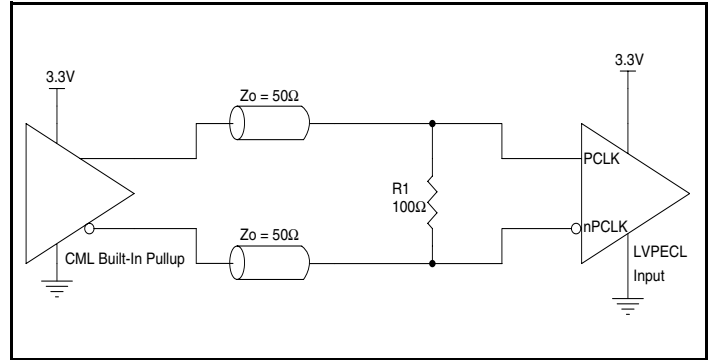


Figure 3B. PCLK/nPCLK Input Driven by a Built-In Pullup CML Driver

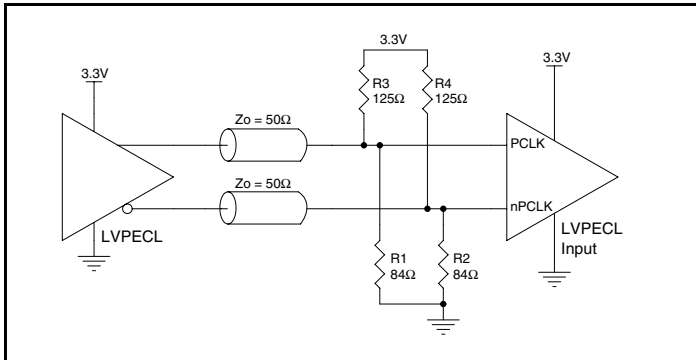


Figure 3C. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver

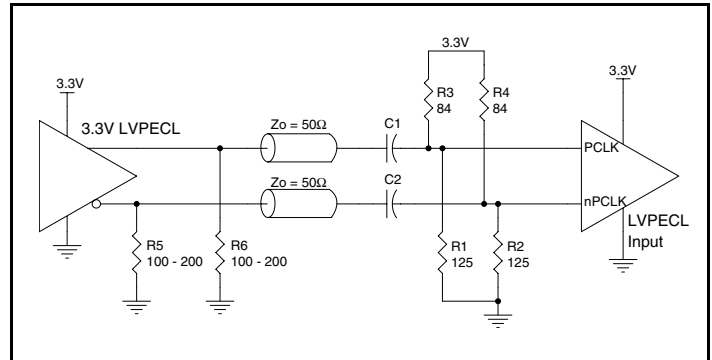


Figure 3D. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver with AC Couple

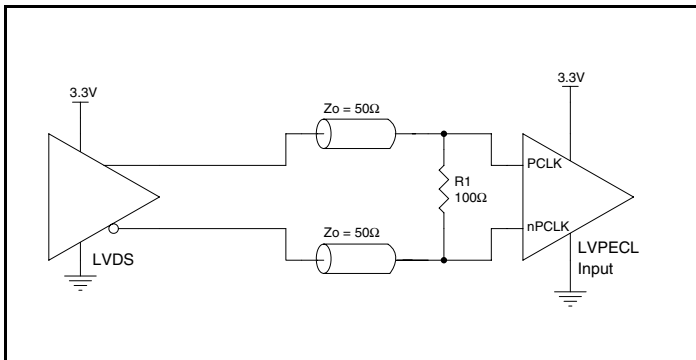


Figure 3E. PCLK/nPCLK Input Driven by a LVDS Driver

2.5V LVPECL Clock Input Interface

The PCLK/nPCLK accepts LVPECL, CML, LVDS and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 4A to 4E* show interface examples for the PCLK/nPCLK input driven by the most common driver types.

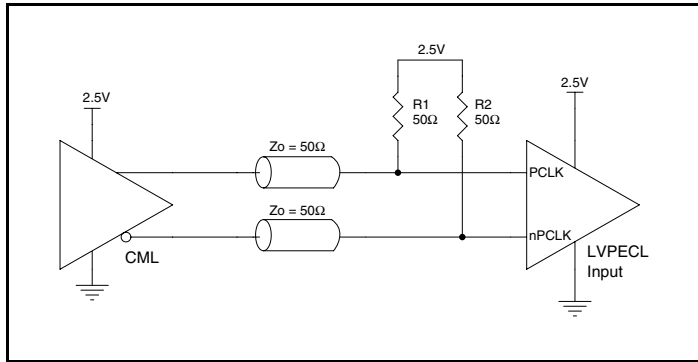


Figure 4A. PCLK/nPCLK Input Driven by an Open Collector CML Driver

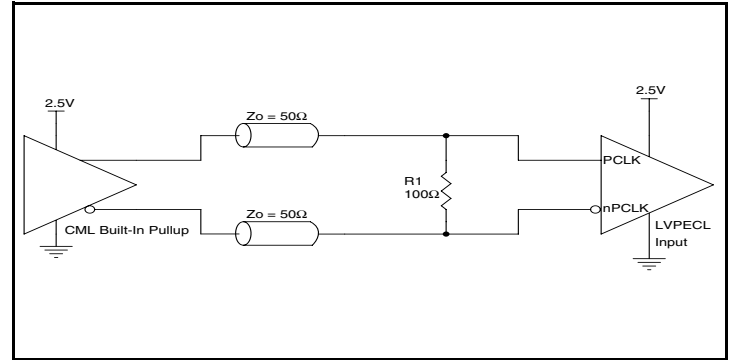


Figure 4B. PCLK/nPCLK Input Driven by a Built-In Pullup CML Driver

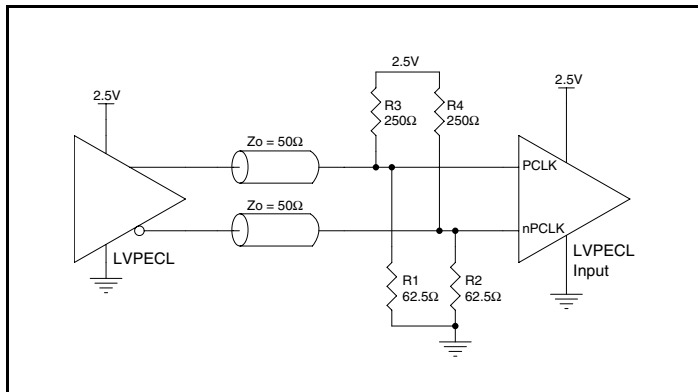


Figure 4C. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver

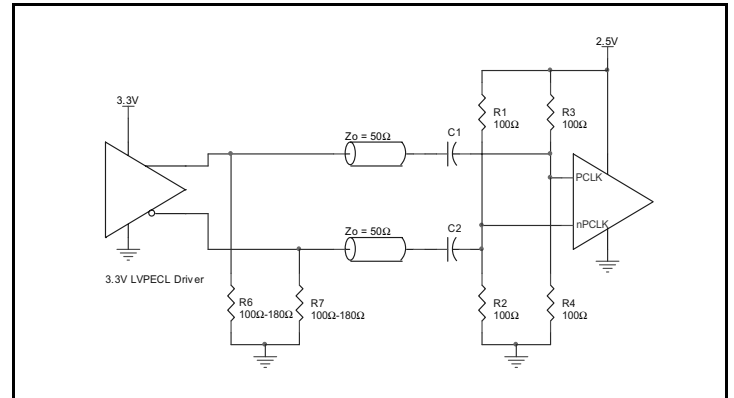


Figure 4D. PCLK/nPCLK Input Driven by a 3.3V LVPECL Driver with AC Couple

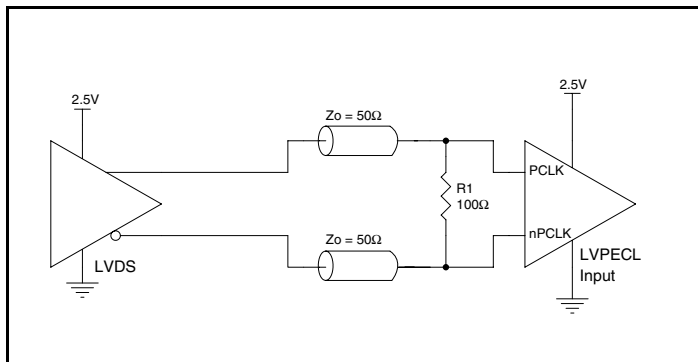


Figure 4E. PCLK/nPCLK Input Driven by a LVDS Driver

The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.

3.3V Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 5A to 5E* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult

with the vendor of the driver component to confirm the driver termination requirements. For example, in Figure 5A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

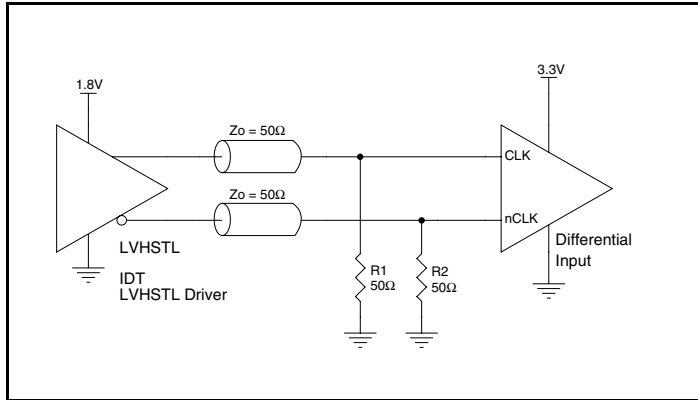


Figure 5A. CLK/nCLK Input Driven by an IDT Open Emitter LVHSTL Driver

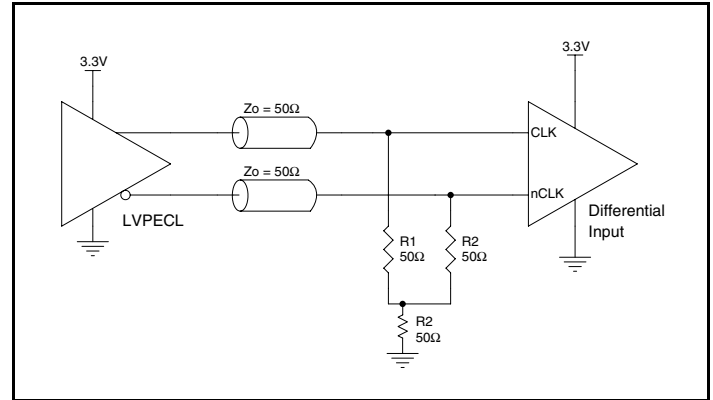


Figure 5B. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

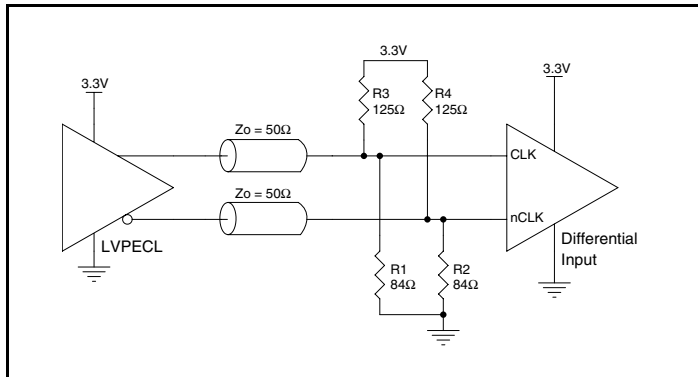


Figure 5C. CLK/nCLK Input Driven by a 3.3V LVPECL Driver

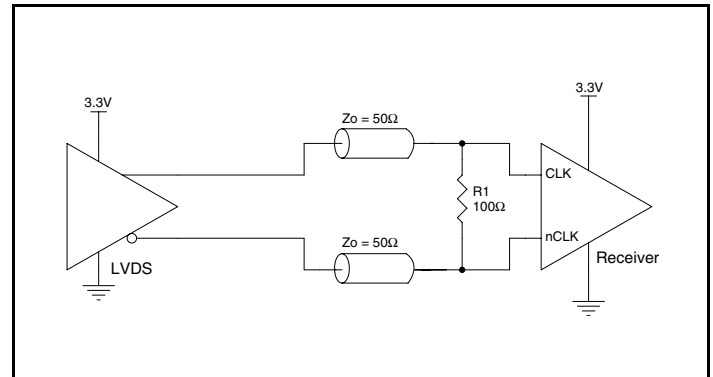


Figure 5D. CLK/nCLK Input Driven by a 3.3V LVDS Driver

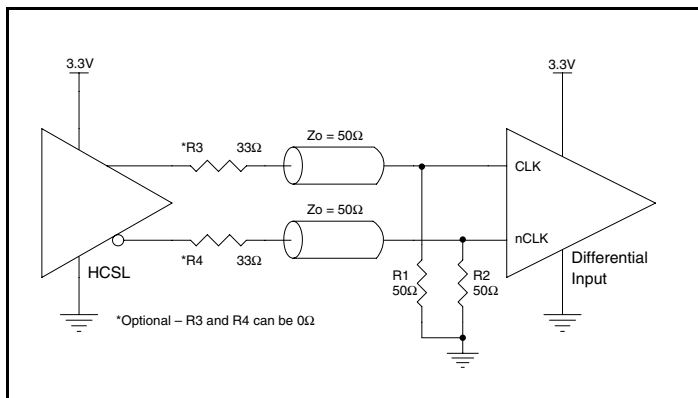


Figure 5E. CLK/nCLK Input Driven by a 3.3V HCSL Driver

2.5V Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. *Figures 6A to 6E* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult

with the vendor of the driver component to confirm the driver termination requirements. For example, in Figure 6A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

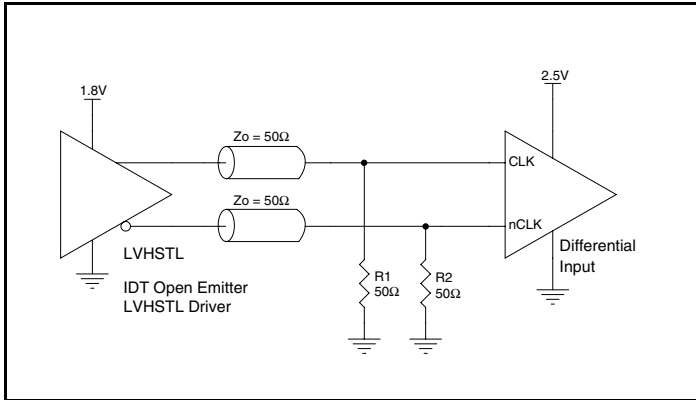


Figure 6A. CLK/nCLK Input Driven by an IDT Open Emitter LVHSTL Driver

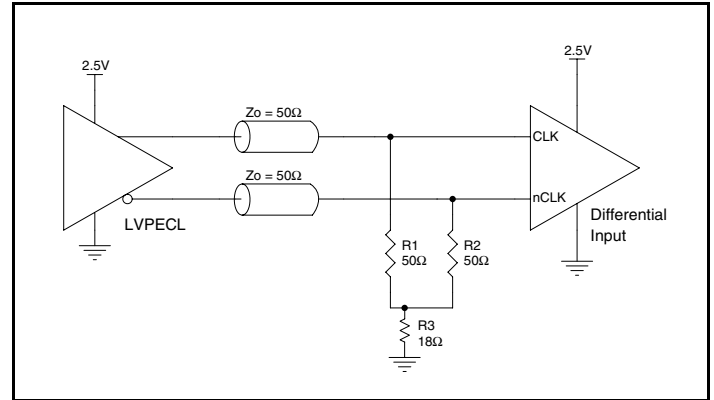


Figure 6B. CLK/nCLK Input Driven by a 2.5V LVPECL Driver

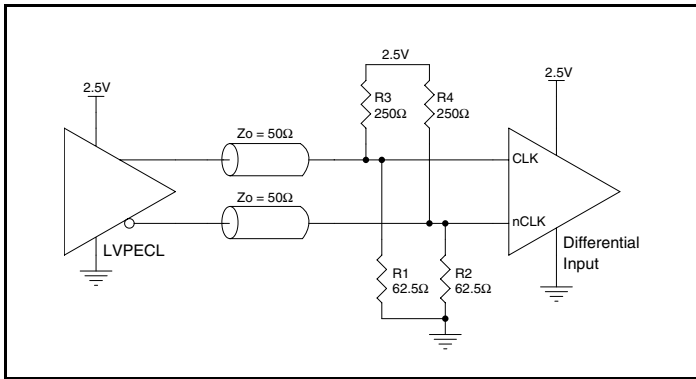


Figure 6C. CLK/nCLK Input Driven by a 2.5V LVPECL Driver

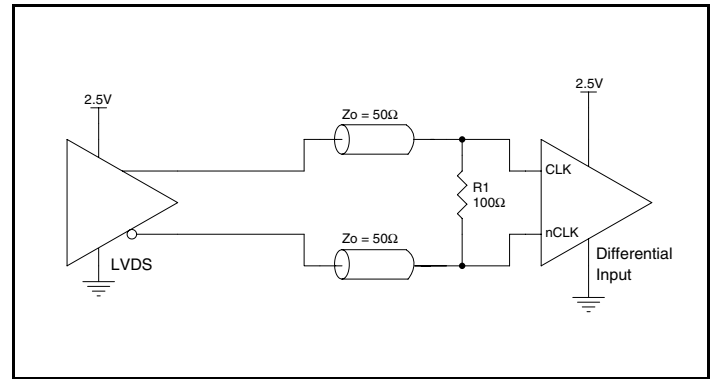


Figure 6D. CLK/nCLK Input Driven by a 2.5V LVDS Driver

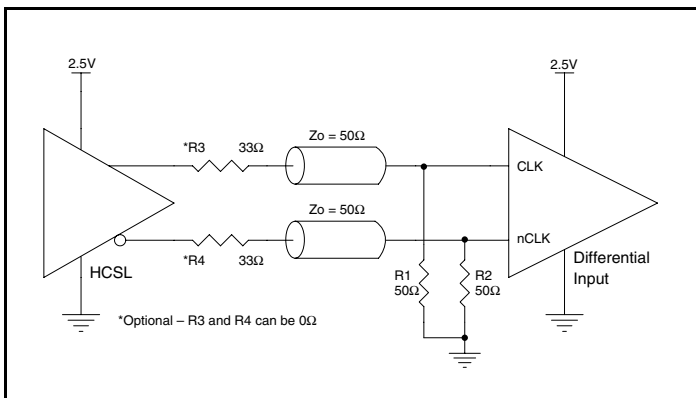
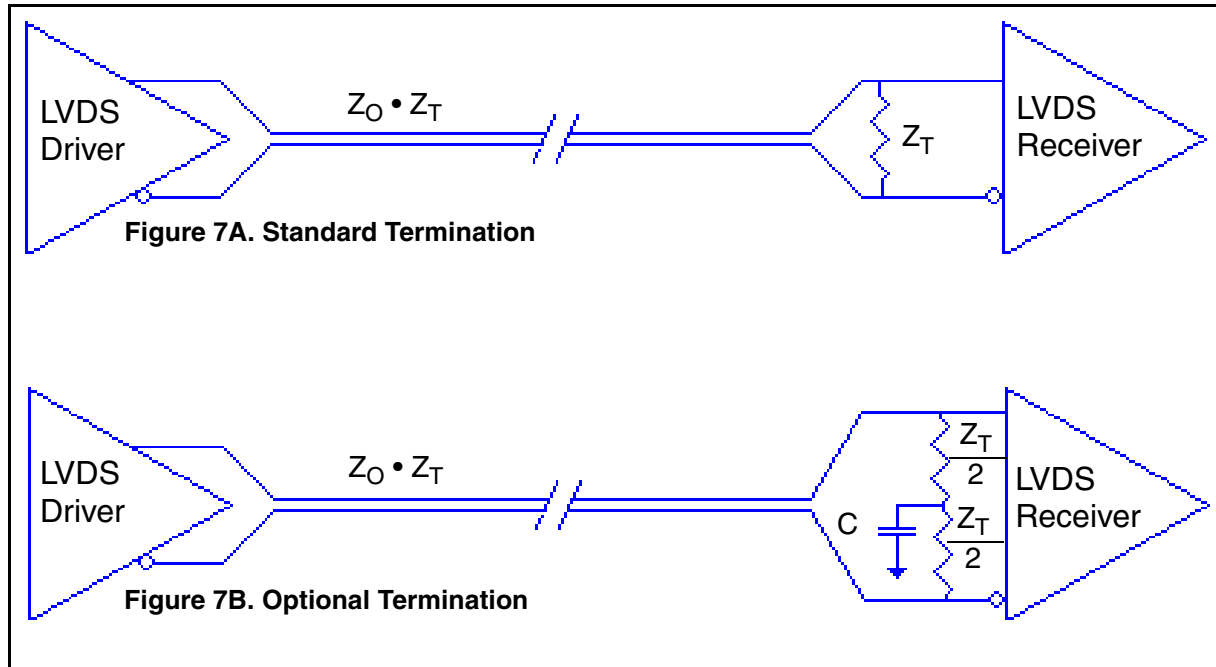


Figure 6E. CLK/nCLK Input Driven by a 2.5V HCSL Driver

LVDS Driver Termination

For a general LVDS interface, the recommended value for the termination impedance (Z_T) is between 90Ω and 132Ω . The actual value should be selected to match the differential impedance (Z_0) of your transmission line. A typical point-to-point LVDS design uses a 100Ω parallel resistor at the receiver and a 100Ω differential transmission-line environment. In order to avoid any transmission-line reflection issues, the components should be be surface mounted and must be placed as close to the receiver as possible. IDT offers a full line of LVDS compliant devices with two types of output structures: current source and voltage source. The

standard termination schematic as shown in *Figure 7A* can be used with either type of output structure. *Figure 7B*, which can also be used with both output types, is an optional termination with center tap capacitance to help filter common mode noise. The capacitor value should be approximately 50pF . If using a non-standard termination, it is recommended to contact IDT and confirm if the output structure is current source or voltage source type. In addition, since these outputs are LVDS compatible, the input receiver's amplitude and common-mode input range should be verified for compatibility with the output.



LVDS Termination

Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion.

Figures 8A and 8B show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

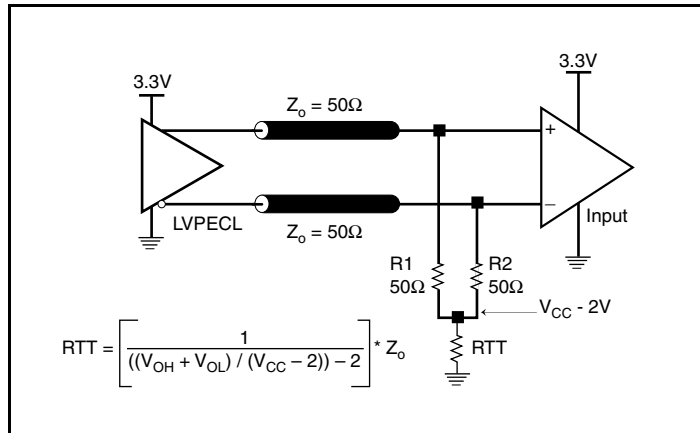


Figure 8A. 3.3V LVPECL Output Termination

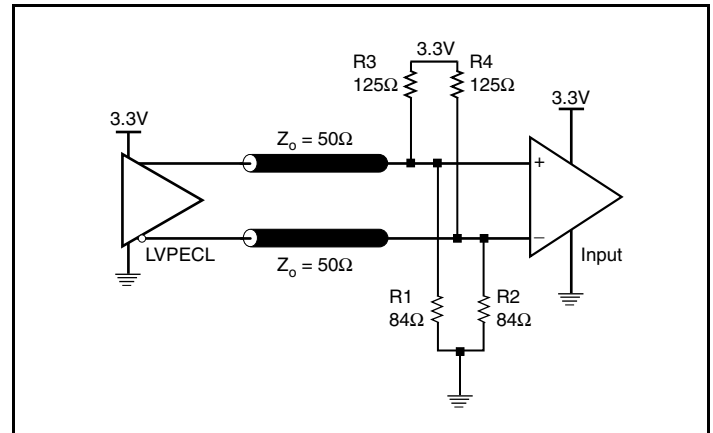


Figure 8B. 3.3V LVPECL Output Termination

Termination for 2.5V LVPECL Outputs

Figure 9A and Figure 9B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating 50Ω to $V_{CC} - 2V$. For $V_{CC} = 2.5V$, the $V_{CC} - 2V$ is very close to ground

level. The $R3$ in Figure 9B can be eliminated and the termination is shown in Figure 9C.

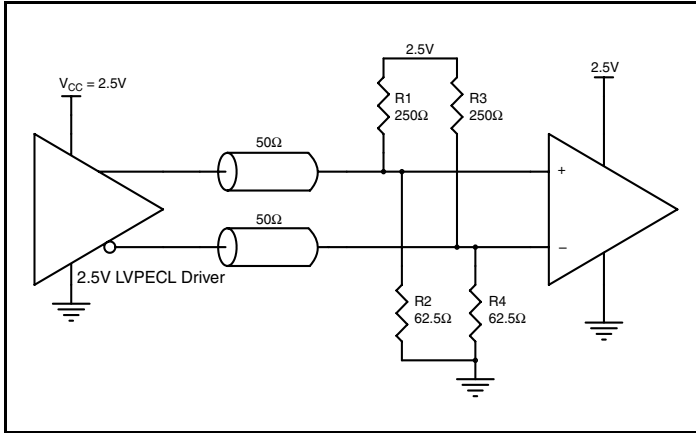


Figure 9A. 2.5V LVPECL Driver Termination Example

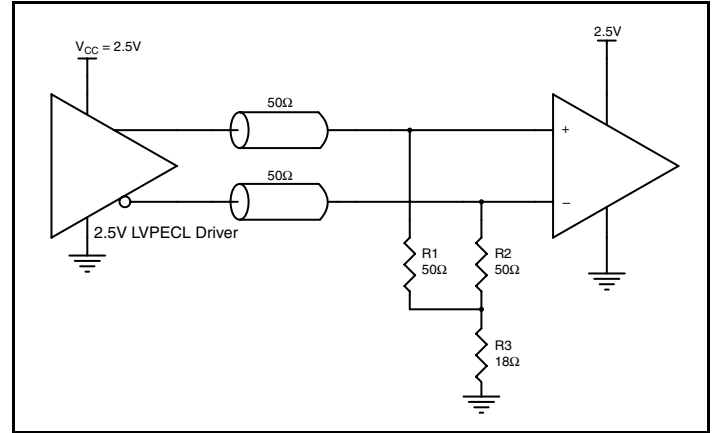


Figure 9B. 2.5V LVPECL Driver Termination Example

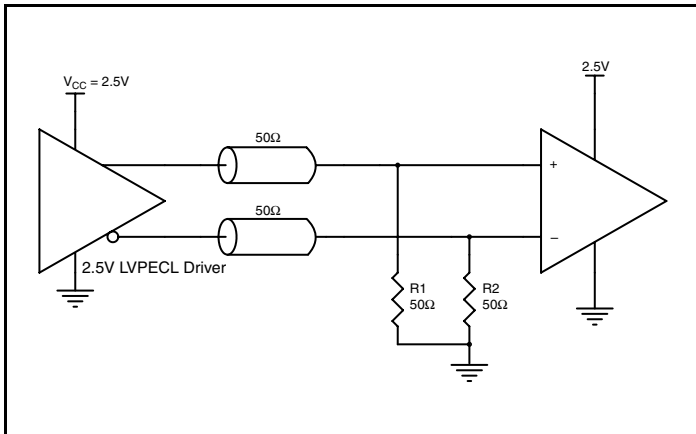


Figure 9C. 2.5V LVPECL Driver Termination Example

VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 10*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as “heat pipes”. The number of vias (i.e. “heat pipes”) are application specific

and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/Electrically Enhance Leadframe Base Package, Amkor Technology.

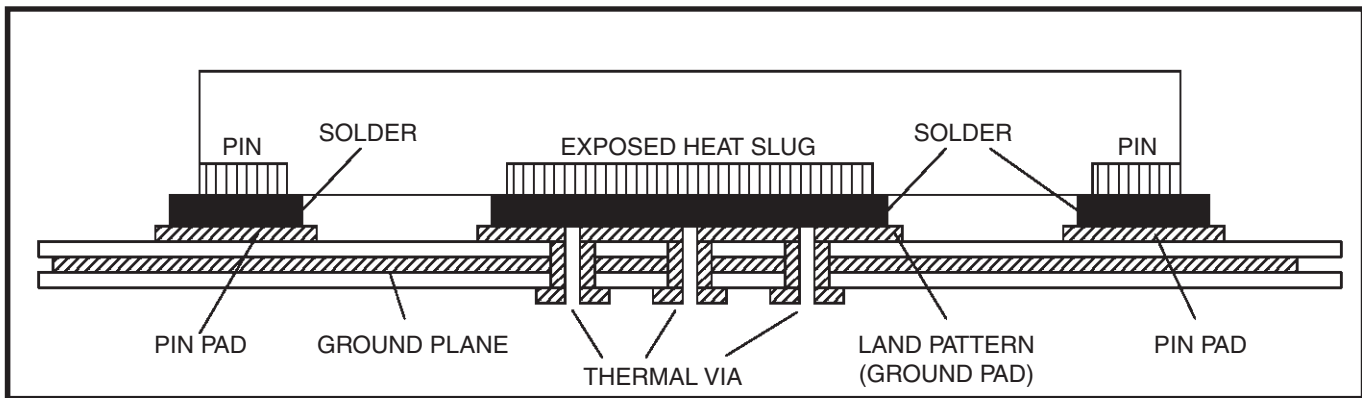


Figure 10. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)

LVPECL Power Considerations

This section provides information on power dissipation and junction temperature for the ICS854S015I-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS854S015I-01 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{EE_MAX} = 3.465V * 85mA = \mathbf{294.53mW}$
- Power (outputs)_{MAX} = **30mW/Loaded Output pair**
If all outputs are loaded, the total power is $5 * 30mW = \mathbf{150mW}$

Total Power_{MAX} (3.3V, with all outputs switching) = $294.53mW + 150mW = \mathbf{444.55mW}$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, T_j , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 49.5°C/W per Table 6 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ\text{C} + 0.445\text{W} * 49.5^\circ\text{C/W} = 107^\circ\text{C. This is below the limit of } 125^\circ\text{C.}$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 24 Lead VFQFN, Forced Convection

| θ_{JA} by Velocity | | | |
|---|----------|----------|----------|
| Meters per Second | 0 | 1 | 2.5 |
| Multi-Layer PCB, JEDEC Standard Test Boards | 49.5°C/W | 43.3°C/W | 38.8°C/W |

3. Calculations and Equations.

The purpose of this section is to calculate the power dissipation for the LVPECL output pair.

LVPECL output driver circuit and termination are shown in *Figure 11*.

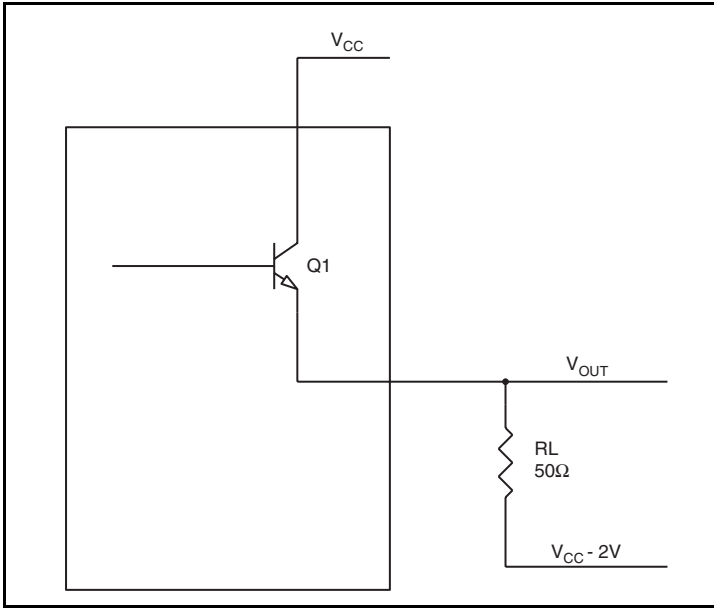


Figure 11. LVPECL Driver Circuit and Termination

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of $V_{CC} - 2V$.

- For logic high, $V_{OUT} = V_{OH_MAX} = V_{CC_MAX} - 0.9V$
 $(V_{CC_MAX} - V_{OH_MAX}) = 0.9V$
- For logic low, $V_{OUT} = V_{OL_MAX} = V_{CC_MAX} - 1.7V$
 $(V_{CC_MAX} - V_{OL_MAX}) = 1.7V$

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - (V_{CC_MAX} - V_{OH_MAX}))/R_L] * (V_{CC_MAX} - V_{OH_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = \mathbf{19.8mW}$$

$$Pd_L = [(V_{OL_MAX} - (V_{CC_MAX} - 2V))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - (V_{CC_MAX} - V_{OL_MAX}))/R_L] * (V_{CC_MAX} - V_{OL_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = \mathbf{10.2mW}$$

$$\text{Total Power Dissipation per output pair} = Pd_H + Pd_L = \mathbf{30mW}$$

LVDS Power Considerations

This section provides information on power dissipation and junction temperature for the ICS854S015I-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS854S015I-01 is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{CC_MAX} = 3.465V * 150mA = 519.75mW$

2. Junction Temperature.

Junction temperature, T_J , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, T_J , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for T_J is as follows: $T_J = \theta_{JA} * Pd_{total} + T_A$

T_J = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_{total} = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 49.5°C/W per Table 7 below.

Therefore, T_J for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ C + 0.520W * 49.5^\circ C/W = 110.7^\circ C. \text{ This is below the limit of } 125^\circ C.$$

This calculation is only an example. T_J will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 7. Thermal Resistance θ_{JA} for 24 Lead VFQFN, Forced Convection

| Meters per Second | θ_{JA} by Velocity | | |
|---|---------------------------|----------|----------|
| | 0 | 1 | 2.5 |
| Multi-Layer PCB, JEDEC Standard Test Boards | 49.5°C/W | 43.3°C/W | 38.8°C/W |

Reliability Information

Table 8. θ_{JA} vs. Air Flow Table for a 24 Lead VFQFN

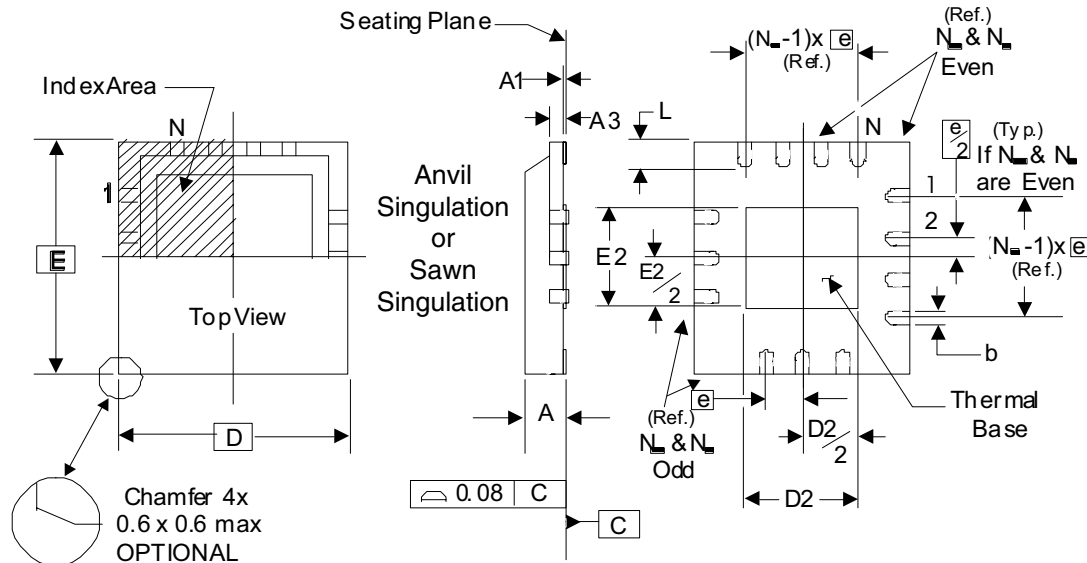
| θ_{JA} vs. Air Flow | | | |
|---|----------|----------|----------|
| Meters per Second | 0 | 1 | 2.5 |
| Multi-Layer PCB, JEDEC Standard Test Boards | 49.5°C/W | 43.3°C/W | 38.8°C/W |

Transistor Count

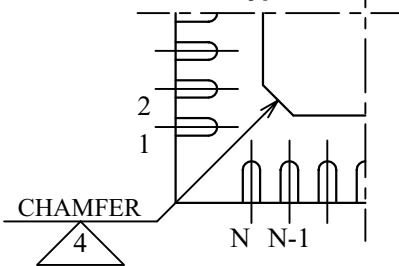
The transistor count for ICS854S015I-01 is: 521

Package Outline and Package Dimensions

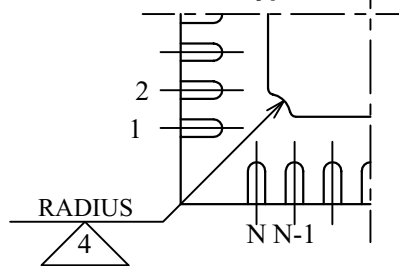
Package Outline - K Suffix for 24 Lead VFQFN



Bottom View w/Type A ID



Bottom View w/Type C ID



There are 2 methods of indicating pin 1 corner at the back of the VFQFN package are:

1. Type A: Chamfer on the paddle (near pin 1)
2. Type C: Mouse bite on the paddle (near pin 1)

Table 9. K Package Dimensions for 24 Lead VFQFN

| All Dimensions in Millimeters | | |
|-------------------------------|----------------|---------|
| Symbol | Minimum | Maximum |
| N | 24 | |
| A | 0.80 | 1.0 |
| A1 | 0 | 0.05 |
| A3 | 0.25 Reference | |
| b | 0.18 | 0.30 |
| e | 0.50 Basic | |
| D, E | 4 | |
| D2, E2 | 2.30 | 2.55 |
| L | 0.30 | 0.50 |
| N_D N_E | 6 | |

Reference Document: JEDEC Publication 95, MO-220

NOTE: The following package mechanical drawing is a generic drawing that applies to any pin count VFQFN package. This drawing is not intended to convey the actual pin count or pin layout of this device. The pin count and pinout are shown on the front page. The package dimensions are in Table 9.

Ordering Information

Table 10. Ordering Information

| Part/Order Number | Marking | Package | Shipping Packaging | Temperature |
|-------------------|---------|---------------------------|--------------------|---------------|
| 854S015CKI-01LF | 15CI01L | "Lead-Free" 24 Lead VFQFN | Tube | -40°C to 85°C |
| 854S015CKI-01LFT | 15CI01L | "Lead-Free" 24 Lead VFQFN | 2500 Tape & Reel | -40°C to 85°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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